

NPN 50mA 120V High Voltage Amplifier transistors

Parameter	Value
V_{CEO}	120V
I _C	50mA

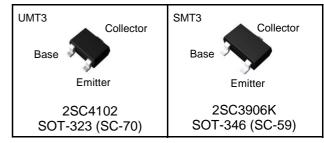
Features

- 1) High Breakdown Voltage (V_{CEO} =120V).
- 2) Complementary PNP Types: 2SA1579 (UMT3) / 2SA1514K (SMT3)
- 3) Complex transistors :

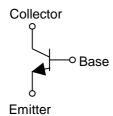
IMX8 (SMT6)

4) Lead Free/RoHS Compliant.

Outline



•Inner circuit



Applications

High Voltage Amplifier

●Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SC4102	UMT3	2021	T106	180	8	3,000	Tx ^{*1}
2SC3906K	SMT3	2928	T146	180	8	3,000	Tx ^{*1}

^{*1} x:h_{FE} rank

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	120	V
Collector-emitter voltage		V _{CEO}	120	V
Emitter-base voltage		V _{EBO}	5	V
O-line to a company		I _C	50	mA
Collector current		I _{CP} *1	100	mA
Power dissipation 2SC4102 2SC3906K		P _D *2	200	mW
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	120	ı	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = 50μA	120	ı	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = 50μA	5	ı	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 100V	-	ı	0.5	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	-	-	0.5	μΑ
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 10 \text{mA}, I_B = 1 \text{mA}$	-	ı	0.5	V
DC current gain	h _{FE}	$V_{CE} = 6V$, $I_C = 2mA$	180	ı	560	-
Transition frequency	f _T	$V_{CE} = 12V$, $I_E = -2mA$ $f=100MH_Z$	ı	140	ı	MHz
Output capacitance	Cob	$V_{CB} = 12V$, $I_E = 0mA$, $f = 1MHz$	-	2.5	-	pF

^{*1} P_W=100ms Single Pulse

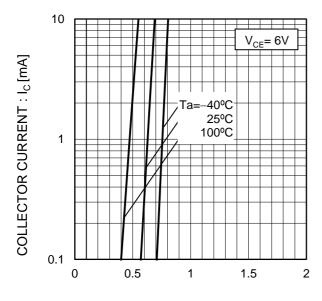
●h_{FE} rank categories

Rank	R	S
h _{FE}	180 to 390	270 to 560

^{*2} Each terminal mounted on a reference footprint

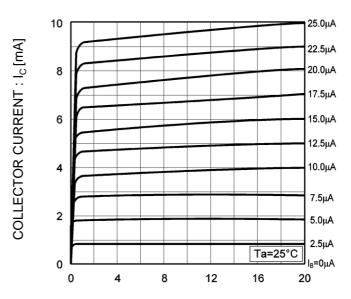
●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics



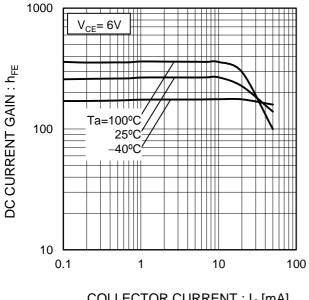
BASE TO EMITTER VOLTAGE : $V_{BE}[V]$

Fig.2 Typical Output Characteristics



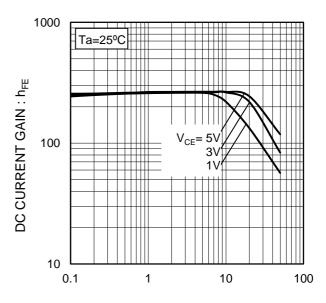
COLECTOR TO EMITTE VOLTAGE : $V_{CE}[V]$

Fig.3 DC Current Gain vs. Collector Current(I)



COLLECTOR CURRENT : I_C [mA]

Fig.4 DC Current Gain vs. Collector Current(II)

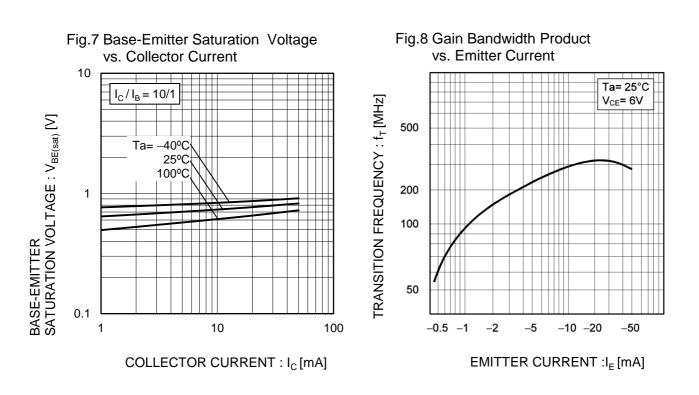


COLLECTOR CURRENT : I_C [mA]

100

●Electrical characteristic curves(Ta = 25°C)

Fig.6 Collector-Emitter Saturation Voltage Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II) vs. Collector Current (I) Ta=25ºC COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] SATURATION VOLTAGE: V_{CE(sat)} [V] $I_{\rm C}/I_{\rm B} = 50/1$ 20/1 Ta=100°C 10/1 25°C -40°C 0.1 0.1 COLLECTOR-EMITTER 0.01 0.01 0.1 10 0.1 10 COLLECTOR CURRENT : I_C [mA] COLLECTOR CURRENT : I_C [mA]



●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs. **Emitter-Base Voltage** Collector output capacitance vs. Collector-Base Voltage 100 COLLECTOR OUTPUT CAPACITANCE: Cob [pF] EMITTER INPUT CAPACITANCE: Cib [pF] Ta=25°C f=1MHz I_C=0A I_E=0A C_{ib} 10 0.1 10 100 COLLECTOR - BASE VOLTAGE : V_{CB} [V] EMITTER - BASE VOLTAGE : V_{EB} [V]

1000 2SC4102 COLLECTOR CURRENT: Ic [mA] 100 10ms 10 DC (Mounted on a 1 reference land) Ta=25°C

Single non repetitive pulse

0.1

Fig.10 Safe Operating Area

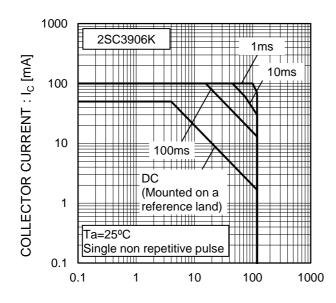
COLLECTOR TO EMITTER VOLTAGE: V_{CE}[V]

100

1000

10

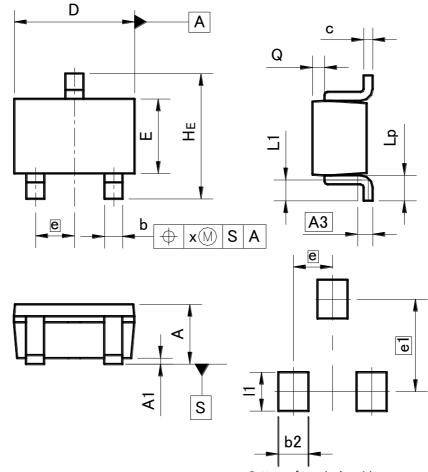
Fig.11 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE: V_{CE}[V]

●Dimensions (Unit:mm)

UMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

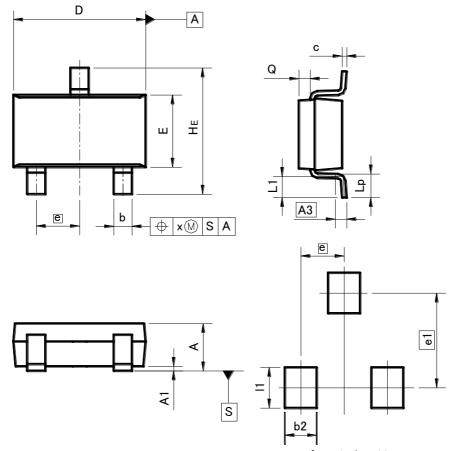
DIM MILIMET		ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.0	10
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
Е	1.15	1.35	0.045	0.053
е	0.0	65	0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
Х		0.10		0.004

DIM	MILIM	IETERS INC		MILIMETERS INCHES		HES
DIM	MIN	MAX	MIN	MAX		
b2	-	0.50	ı	0.020		
e1	1.55		0.0	61		
l1	-	0.65	-	0.026		

Dimension in mm / inches

●Dimensions (Unit : mm)





Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	DIM MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.0	10
b	0.35	0.50	0.014	0.020
С	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
е	0.9	95	0.0	37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
Х	_	0.10	_	0.004
У	_	0.10	_	0.004

DIM	MILIMI	ETERS	INCHES	
MIN		MAX	MIN	MAX
b2	_	0.60	-	0.024
e1	2.10		0.0	83
l1	_	0.90	_	0.035

Dimension in mm / inches

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